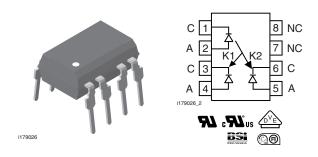


Linear Optocoupler, High Gain Stability, Wide Bandwidth



DESCRIPTION

The IL300 linear optocoupler consists of an AlGaAs IRLED irradiating an isolated feedback and an output PIN photodiode in a bifurcated arrangement. The feedback photodiode captures a percentage of the LEDs flux and generates a control signal (I_{P1}) that can be used to servo the LED drive current. This technique compensates for the LED's non-linear, time, and temperature characteristics. The output PIN photodiode produces an output signal (I_{P2}) that is linearly related to the servo optical flux created by the LED.

The time and temperature stability of the input-output coupler gain (K3) is insured by using matched PIN photodiodes that accurately track the output flux of the LED.

FEATURES

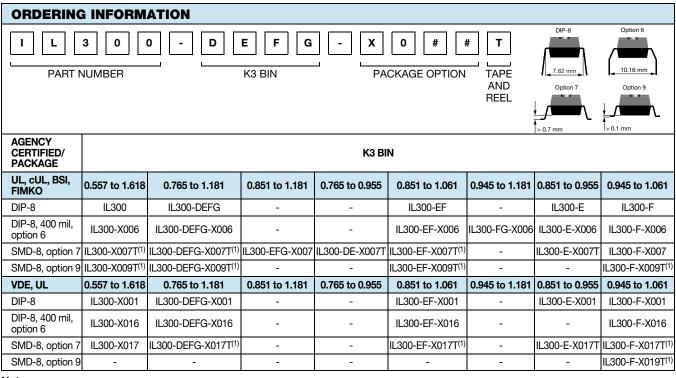
- Couples AC and DC signals
- 0.01 % servo linearity
- Wide bandwidth, > 200 kHz
- High gain stability, ± 0.005 %/°C typically
- Low input-output capacitance
- Low power consumption, < 15 mW
- Isolation test voltage, 5300 $V_{\text{RMS}},$ 1 s
- Internal insulation distance, > 0.4 mm
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

APPLICATIONS

- Power supply feedback voltage/current
- Medical sensor isolation
- Audio signal interfacing
- Isolated process control transducers
- Digital telephone isolation

AGENCY APPROVALS

- UL file no. E52744, system code H
- DIN EN 60747-5-2 (VDE 0884)
- DIN EN 60747-5-5 (pending) available with option 1
- BSI
- FIMKO



Note

⁽¹⁾ Also available in tubes, do not put "T" on the end.

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ROHS COMPLIANT



OPERATION DESCRIPTION

A typical application circuit (figure 1) uses an operational amplifier at the circuit input to drive the LED. The feedback photodiode sources current to R1 connected to the inverting input of U1. The photocurrent, I_{P1} , will be of a magnitude to satisfy the relationship of ($I_{P1} = V_{IN}/R1$).

The magnitude of this current is directly proportional to the feedback transfer gain (K1) times the LED drive current $(V_{IN}/R1 = K1 \times I_F)$. The op-amp will supply LED current to force sufficient photocurrent to keep the node voltage (Vb) equal to Va.

The output photodiode is connected to a non-inverting voltage follower amplifier. The photodiode load resistor, R2, performs the current to voltage conversion. The output amplifier voltage is the product of the output forward gain (K2) times the LED current and photodiode load, R2 ($V_{O} = I_{F} \times K2 \times R2$).

Therefore, the overall transfer gain (V_O/V_{IN}) becomes the ratio of the product of the output forward gain (K2) times the photodiode load resistor (R2) to the product of the feedback transfer gain (K1) times the input resistor (R1). This reduces to

 $V_O/V_{IN} = (K2 \times R2)/(K1 \times R1).$

The overall transfer gain is completely independent of the LED forward current. The IL300 transfer gain (K3) is expressed as the ratio of the output gain (K2) to the feedback gain (K1). This shows that the circuit gain becomes the product of the IL300 transfer gain times the ratio of the output to input resistors

 $V_0/V_{IN} = K3 (R2/R1).$

K1-SERVO GAIN

The ratio of the input photodiode current (I_{P1}) to the LED current (I_F) i.e., K1 = I_{P1}/I_F .

K2-FORWARD GAIN

The ratio of the output photodiode current (I_{P2}) to the LED current (I_F), i.e., K2 = I_{P2}/I_F .

K3-TRANSFER GAIN

The transfer gain is the ratio of the forward gain to the servo gain, i.e., K3 = K2/K1.

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∆K3-TRANSFER FAIN LINEARITY

The percent deviation of the transfer gain, as a function of LED or temperature from a specific transfer gain at a fixed LED current and temperature.

PHOTODIODE

A silicon diode operating as a current source. The output current is proportional to the incident optical flux supplied by the LED emitter. The diode is operated in the photovoltaic or photoconductive mode. In the photovoltaic mode the diode functions as a current source in parallel with a forward biased silicon diode.

The magnitude of the output current and voltage is dependent upon the load resistor and the incident LED optical flux. When operated in the photoconductive mode the diode is connected to a bias supply which reverse biases the silicon diode. The magnitude of the output current is directly proportional to the LED incident optical flux.

LED (LIGHT EMITTING DIODE)

An infrared emitter constructed of AlGaAs that emits at 890 nm operates efficiently with drive current from 500 μ A to 40 mA. Best linearity can be obtained at drive currents between 5 mA to 20 mA. Its output flux typically changes by - 0.5 %/°C over the above operational current range.

APPLICATION CIRCUIT

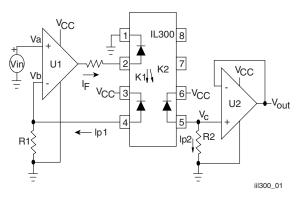


Fig. 1 - Typical Application Circuit



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT	<u> </u>					
Power dissipation		P _{diss}	160	mW		
Derate linearly from 25 °C			2.13	mW/°C		
Forward current		IF	60	mA		
Surge current (pulse width < 10 µs)		I _{PK}	250	mA		
Reverse voltage		V _R	5	V		
Thermal resistance		R _{th}	470	K/W		
Junction temperature		Тj	100	°C		
OUTPUT	<u> </u>					
Power dissipation		P _{diss}	50	mW		
Derate linearly from 25 °C			0.65	mW/°C		
Reverse voltage		V _R	50	V		
Thermal resistance		R _{th}	1500	K/W		
Junction temperature		Тj	100	°C		
COUPLER	<u> </u>					
Total package dissipation at 25 °C		Ptot	210	mW		
Derate linearly from 25 °C			2.8	mW/°C		
Storage temperature		T _{stg}	- 55 to + 150	°C		
Operating temperature		T _{amb}	- 55 to + 100	°C		
Isolation test voltage		V _{ISO}	> 5300	V _{RMS}		
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	> 10 ¹²	Ω		
ISUIALIULI TESISLATICE	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	> 10 ¹¹	Ω		

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT (LED EMITTER)						
Forward voltage	I _F = 10 mA	V _F		1.25	1.50	V
V _F temperature coefficient		$\Delta V_F / \Delta^\circ C$		- 2.2		mV/°C
Reverse current	V _R = 5 V	I _R		1		μA
Junction capacitance	V _F = 0 V, f = 1 MHz	Cj		15		pF
Dynamic resistance	I _F = 10 mA	$\Delta V_F / \Delta I_F$		6		Ω
OUTPUT						
Dark current	V _{det} = - 15 V, I _F = 0 A	Ι _D		1	25	nA
Open circuit voltage	I _F = 10 mA	VD		500		mV
Short circuit current	I _F = 10 mA	I _{SC}		70		μA
Junction capacitance	V _F = 0 V, f = 1 MHz	Cj		12		pF
Noise equivalent power	V _{det} = 15 V	NEP		4 x 10 ⁻¹⁴		W/√Hz
COUPLER						
Input-output capacitance	V _F = 0 V, f = 1 MHz			1		pF
K1, servo gain (I_{P1}/I_F) $I_F = 10 \text{ mA}, V_{det} = -15 \text{ V}$		K1	0.0050	0.007	0.011	
Servo current ⁽¹⁾⁽²⁾	I _F = 10 mA, V _{det} = - 15 V	I _{P1}		70		μA
K2, forward gain (I_{P2}/I_F)	I _F = 10 mA, V _{det} = - 15 V	K2	0.0036	0.007	0.011	
Forward current	I _F = 10 mA, V _{det} = - 15 V	I _{P2}		70		μA
K3, transfer gain (K2/K1) ⁽¹⁾⁽²⁾	I _F = 10 mA, V _{det} = - 15 V	K3	0.56	1	1.65	K2/K1



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ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
COUPLER							
Transfer gain stability	I _F = 10 mA, V _{det} = - 15 V	Δ K3/ Δ T _A		± 0.005	± 0.05	%/°C	
	I _F = 1 mA to 10 mA	ΔK3		± 0.25		%	
Transfer gain linearity	I _F = 1 mA to 10 mA, T _{amb} = 0 °C to 75 °C			± 0.5		%	
PHOTOCONDUCTIVE OPERATION							
Frequency response	I_{Fq} = 10 mA, MOD = ± 4 mA, R _L = 50 Ω	BW (- 3 db)		200		kHz	
Phase response at 200 kHz	V _{det} = - 15 V			- 45		Deg.	

Notes

• Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

⁽¹⁾ Bin sorting:

K3 (transfer gain) is sorted into bins that are ± 6 %, as follows:

Bin A = 0.557 to 0.626Bin B = 0.620 to 0.696Bin C = 0.690 to 0.773

Bin D = 0.765 to 0.859Bin E = 0.851 to 0.955Bin F = 0.945 to 1.061Bin G = 1.051 to 1.181

- Bin H = 1.169 to 1.311Bin L = 1.297 to 1.456
- Bin I = 1.297 to 1.456 Bin J = 1.442 to 1.618

K3 = K2/K1. K3 is tested at I_F = 10 mA, V_{det} = -15 V.

⁽²⁾ Bin categories: All IL300s are sorted into a K3 bin, indicated by an alpha character that is marked on the part. The bins range from "A" through "J".

The IL300 is shipped in tubes of 50 each. Each tube contains only one category of K3. The category of the parts in the tube is marked on the tube label as well as on each individual part.

⁽³⁾ Category options: standard IL300 orders will be shipped from the categories that are available at the time of the order. Any of the ten categories may be shipped. For customers requiring a narrower selection of bins, the bins can be grouped together as follows:

IL300-DEFG: order this part number to receive categories D, E, F, G only.

IL300-EF: order this part number to receive categories E, F only.

IL300-E: order this part number to receive category E only.

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Switching time	$\Delta I_F = 2$ mA, $I_{Fq} = 10$ mA	t _r		1		μs	
		t _f		1		μs	
Rise time		t _r		1.75		μs	
Fall time		t _f		1.75		μs	

COMMON MODE TRANSIENT IMMUNITY								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Common mode capacitance	$V_F = 0 V, f = 1 MHz$	C _{CM}		0.5		pF		
Common mode rejection ratio	f = 60 Hz, R_L = 2.2 k Ω	CMRR		130		dB		



TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

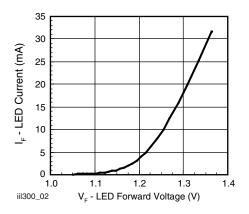


Fig. 2 - LED Forward Current vs. Forward Voltage

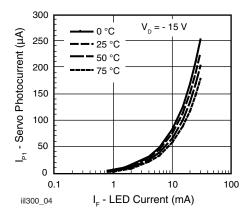


Fig. 3 - Servo Photocurrent vs. LED Current and Temperature

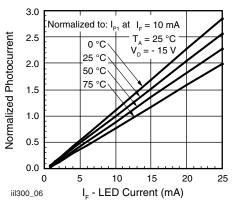


Fig. 4 - Normalized Servo Photocurrent vs. LED Current and Temperature

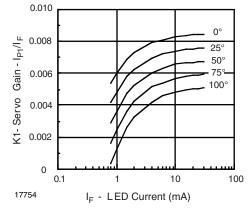


Fig. 5 - Servo Gain vs. LED Current and Temperature

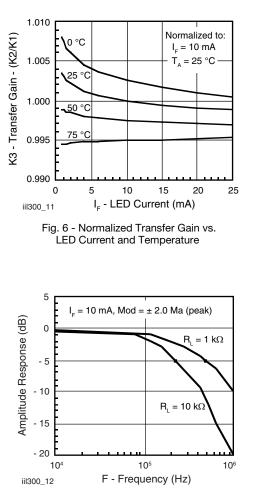


Fig. 7 - Amplitude Response vs. Frequency

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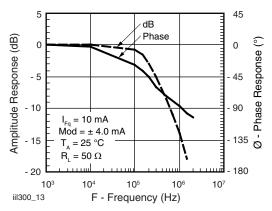


Fig. 8 - Amplitude and Phase Response vs. Frequency

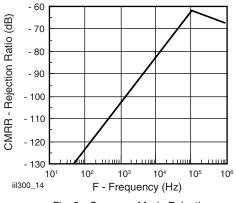


Fig. 9 - Common-Mode Rejection

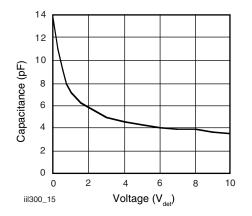


Fig. 10 - Photodiode Junction Capacitance vs. Reverse Voltage

APPLICATION CONSIDERATIONS

In applications such as monitoring the output voltage from a line powered switch mode power supply, measuring bioelectric signals, interfacing to industrial transducers, or making floating current measurements, a galvanically isolated, DC coupled interface is often essential. The IL300 can be used to construct an amplifier that will meet these needs.

The IL300 eliminates the problems of gain nonlinearity and drift induced by time and temperature, by monitoring LED output flux.

A pin photodiode on the input side is optically coupled to the LED and produces a current directly proportional to flux falling on it. This photocurrent, when coupled to an amplifier, provides the servo signal that controls the LED drive current.

The LED flux is also coupled to an output PIN photodiode. The output photodiode current can be directly or amplified to satisfy the needs of succeeding circuits.

ISOLATED FEEDBACK AMPLIFIER

The IL300 was designed to be the central element of DC coupled isolation amplifiers. Designing the IL300 into an amplifier that provides a feedback control signal for a line powered switch mode power is quite simple, as the following example will illustrate.

See figure 12 for the basic structure of the switch mode supply using the Infineon TDA4918 push-pull switched power supply control cChip. Line isolation are provided by the high frequency transformer. The voltage monitor isolation will be provided by the IL300.

The isolated amplifier provides the PWM control signal which is derived from the output supply voltage. Figure 13 more closely shows the basic function of the amplifier.

The control amplifier consists of a voltage divider and a non-inverting unity gain stage. The TDA4918 data sheet indicates that an input to the control amplifier is a high quality operational amplifier that typically requires a + 3 V signal. Given this information, the amplifier circuit topology shown in figure 14 is selected.

The power supply voltage is scaled by R1 and R2 so that there is + 3 V at the non-inverting input (V_a) of U1. This voltage is offset by the voltage developed by photocurrent flowing through R3. This photocurrent is developed by the optical flux created by current flowing through the LED. Thus as the scaled monitor voltage (V_a) varies it will cause a change in the LED current necessary to satisfy the differential voltage needed across R3 at the inverting input. The first step in the design procedure is to select the value of R3 given the LED quiescent current (I_{Fq}) and the servo gain (K1). For this design, I_{Fq} = 12 mA. Figure 4 shows the servo photocurrent at I_{Fq} is found to be 100 mA. With this data R3 can be calculated.

R3 =
$$\frac{V_b}{I_{Pl}} = \frac{3 V}{100 \ \mu A} = 30 \ k\Omega$$

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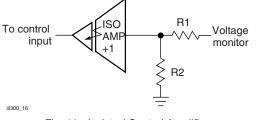


Fig. 11 - Isolated Control Amplifier

For best input offset compensation at U1, R2 will equal R3. The value of R1 can easily be calculated from the following.

$$R1 = R2 x \left(\frac{V_{MONITOR}}{V_a} - 1\right)$$

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The value of R5 depends upon the IL300 Transfer Gain (K3). K3 is targeted to be a unit gain device, however to minimize the part to part Transfer Gain variation, Infineon offers K3 graded into \pm 5 % bins. R5 can determined using the following equation,

$$R5 = \frac{V_{OUT}}{V_{MONITOR}} x \frac{R3 x (R1 + R2)}{R2 x K3}$$

or if a unity gain amplifier is being designed ($V_{MONITOR} = V_{OUT}$, R1 = 0), the equation simplifies to:

$$R5 = \frac{R3}{K3}$$

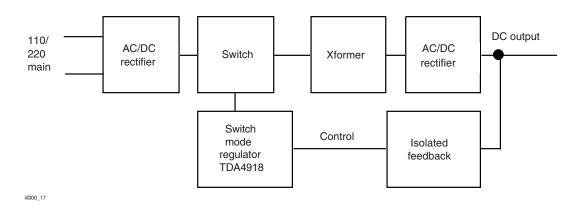


Fig. 12 - Switching Mode Power Supply

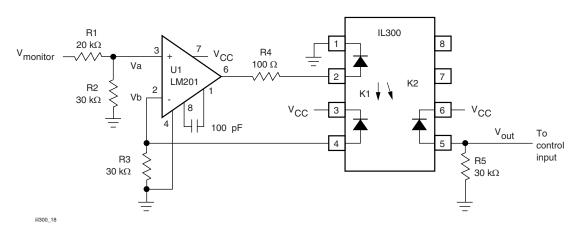


Fig. 13 - DC Coupled Power Supply Feedback Amplifier

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Table 1. Gives the value of R5 given the production K3 bin.

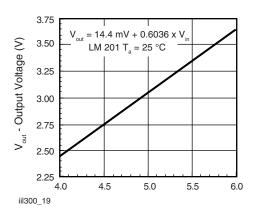
BIN		К3		R5 RESISTOR
DIN	MIN.	MAX.	TYP.	1 % kΩ
А	0.560	0.623	0.59	51.1
В	0.623	0.693	0.66	45.3
С	0.693	0.769	0.73	41.2
D	0.769	0.855	0.81	37.4
E	0.855	0.950	0.93	32.4
F	0.950	1.056	1	30
G	1.056	1.175	1.11	27
Н	1.175	1.304	1.24	24
I	1.304	1.449	1.37	22
J	1.449	1.610	1.53	19.4

The last step in the design is selecting the LED current limiting resistor (R4). The output of the operational amplifier is targeted to be 50 % of the V_{CC} , or 2.5 V. With an LED quiescent current of 12 mA the typical LED (V_F) is 1.3 V. Given this and the operational output voltage, R4 can be calculated.

R4 =
$$\frac{V_{opamp} - V_F}{I_{Fq}} = \frac{2.5 \text{ V} - 1.3 \text{ V}}{12 \text{ mA}} = 100 \Omega$$

The circuit was constructed with an LM201 differential operational amplifier using the resistors selected. The amplifier was compensated with a 100 pF capacitor connected between pins 1 and 8.

The DC transfer characteristics are shown in figure 17. The amplifier was designed to have a gain of 0.6 and was measured to be 0.6036. Greater accuracy can be achieved by adding a balancing circuit, and potentiometer in the input divider, or at R5. The circuit shows exceptionally good gain linearity with an RMS error of only 0.0133 % over the input voltage range of 4 V to 6 V in a servo mode; see figure 15.





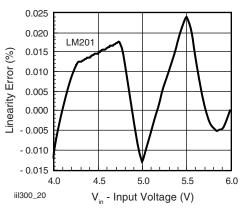


Fig. 15 - Linearity Error vs. Input Voltage

The AC characteristics are also quite impressive offering a - 3 dB bandwidth of 100 kHz, with a - 45° phase shift at 80 kHz as shown in figure 16.

8



2 45 dB Phase Amplitude Response (dB) 0 0 Phase Response (°) - 2 45 - 4 90 - 6 135 Ē - 8 - 180 10⁵ 10 10⁶ 10 iil300_21 F - Frequency (Hz)

Fig. 16 - Amplitude and Phase Power Supply Control

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The same procedure can be used to design isolation amplifiers that accept bipolar signals referenced to ground. These amplifiers circuit configurations are shown in figure 17. In order for the amplifier to respond to a signal that swings above and below ground, the LED must be pre biased from a separate source by using a voltage reference source (V_{ref1}). In these designs, R3 can be determined by the following equation.

$$R3 = \frac{V_{ref1}}{I_{P1}} = \frac{V_{ref1}}{K1I_{Fq}}$$

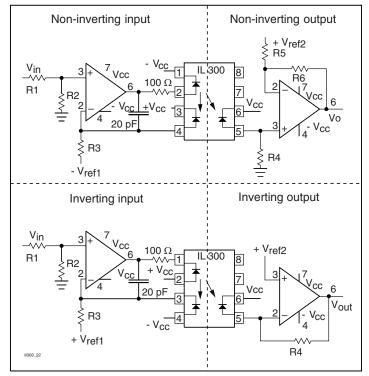


Fig. 17 - Non-inverting and Inverting Amplifiers

TABLE 2 - OPTOLINEAR AMPLIEFIERS							
AMPLIFIER	INPUT	OUTPUT	GAIN	OFFSET			
Non-inverting	Inverting	Inverting	$\frac{V_{OUT}}{V_{IN}} = \frac{K3 \times R4 \times R2}{R3 \times (R1 \times R2)}$	$V_{ref2} = \frac{V_{ref1} \times R4 \times K3}{R3}$			
Non-inverting	Non-inverting	Non-inverting	$\frac{V_{OUT}}{V_{IN}} = \frac{K3 \text{ x } R4 \text{ x } R2 \text{ x } (R5 + R6)}{R3 \text{ x } R5 \text{ x } (R1 \text{ x } R2)}$	$V_{ref2} = \frac{-V_{ref1} \times R4 \times (R5 + R6) \times K3}{R3 \times R6}$			
Inverting	Inverting	Non-inverting	$\frac{V_{OUT}}{V_{IN}} = \frac{-K3 \times R4 \times R2 \times (R5 + R6)}{R3 \times (R1 \times R2)}$	$V_{ref2} = \frac{V_{ref1} \times R4 \times (R5 + R6) \times K3}{R3 \times R6}$			
Inverting	Non-inverting	Inverting	$\frac{V_{OUT}}{V_{IN}} = \frac{-K3 \times R4 \times R2}{R3 \times (R1 \times R2)}$	$V_{ref2} = \frac{-V_{ref1} \times R4 \times K3}{R3}$			

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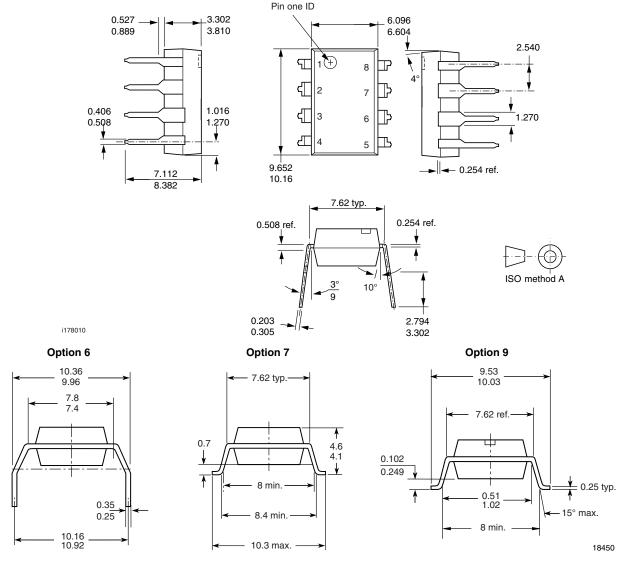
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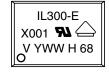
These amplifiers provide either an inverting or non-inverting transfer gain based upon the type of input and output amplifier. Table 2 shows the various configurations along with the specific transfer gain equations. The offset column refers to the calculation of the output offset or V_{ref2} necessary to provide a zero voltage output for a zero voltage input. The non-inverting input amplifier requires the use of a bipolar supply, while the inverting input stage can be implemented with single supply operational amplifiers that permit operation close to ground.

For best results, place a buffer transistor between the LED and output of the operational amplifier when a CMOS opamp is used or the LED I_{Fq} drive is targeted to operate beyond 15 mA. Finally the bandwidth is influenced by the magnitude of the closed loop gain of the input and output amplifiers. Best bandwidths result when the amplifier gain is designed for unity.

PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (this is an example of the IL300-E-X001)





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